



Graphene On Germanium As Substrate For Analog Electronics

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The Invention

Electrically conductive material structures, analog electronic devices incorporating the structures and methods for making the structures are provided. The structures include a layer of graphene on a semiconductor substrate. The graphene layer and the substrate are separated by an interfacial region that promotes transfer of charge carriers from the surface of the substrate to the graphene.

Additional Information

For More Information About the Inventors

- [Max Lagally](#).

Tech Fields

- [Semiconductors & Integrated Circuits : Components & materials](#)

For current licensing status, please contact Jeanine Burmania at jeanine@warf.org or 608-960-9846